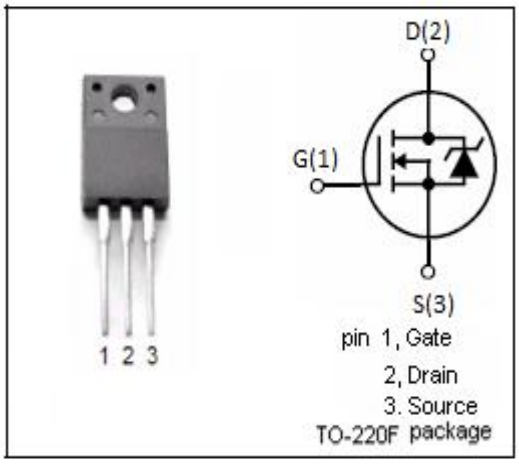
Isc N-Channel MOSFET Transistor IPA083N10N5

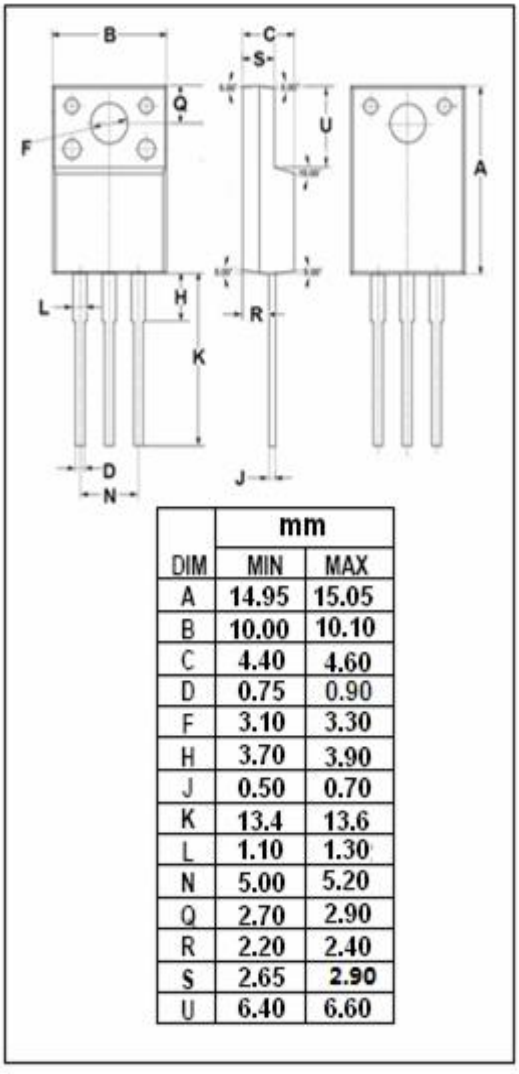


• FEATURES

- With To-220F package
- Low input capacitance and gate charge
- Low gate input resistance
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

• APPLICATIONS

- Switching applications



DIM	mm MIN	mm MAX
A	14.95	15.05
B	10.00	10.10
C	4.40	4.60
D	0.75	0.90
F	3.10	3.30
H	3.70	3.90
J	0.50	0.70
K	13.4	13.6
L	1.10	1.30
N	5.00	5.20
Q	2.70	2.90
R	2.20	2.40
S	2.65	2.90
U	6.40	6.60

• ABSOLUTE MAXIMUM RATINGS(T_a=25℃)

SYMBOL	PARAMETER	VALUE	UNIT
V_{DSS}	Drain-Source Voltage	100	V
V_{GSS}	Gate-Source Voltage	±20	V
I_D	Drain Current-Continuous@T_C=25℃ T_C=100℃	44 32	A
I_{DM}	Drain Current-Single Pulsed	176	A
P_D	Total Dissipation @T_C=25℃	36	W
Tj	Max. Operating Junction Temperature	175	℃
T_{stg}	Storage Temperature	-55~175	℃

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(ch-c)	Channel-to-case thermal resistance	4.1	℃/W
Rth(ch-a)	Channel-to-ambient thermal resistance	62.5	℃/W

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ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
BV_{DSS}	Drain-Source Breakdown Voltage	V_{GS}=0V; I_D=1mA	100			V
$V_{GS(th)}$	Gate Threshold Voltage	V_{DS}=±20V; I_D=0.05mA	2.2		3.8	V
$R_{DS(on)}$	Drain-Source On-Resistance	V_{GS}= 10V; I_D=44A		7.2	8.3	mΩ
I_{GSS}	Gate-Source Leakage Current	V_{GS}= ±20V;V_{DS}= 0V			±0.1	μA
I_{DSS}	Drain-Source Leakage Current	V_{DS}= 100V; V_{GS}= 0V;Tj=25℃ Tj=125℃			1 100	μA
V_{SDF}	Diode forward voltage	I_{SD}=44A, V_{GS} = 0 V			1.2	V

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